



SANYO Semiconductors

DATA SHEET

2SA2180 — PNP Epitaxial Planar Silicon Transistor

50V / 5A High-Speed Switching Applications

Applications

- High-speed switching applications (switching regulator, driver circuit).

Features

- Adoption of MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		-50	V
Collector-to-Emitter Voltage	V _{CEO}		-50	V
Emitter-to-Base Voltage	V _{EBO}		-6	V
Collector Current	I _C		-5	A
Collector Current (Pulse)	I _{CP}		-8	A
Base Current	I _B		-1	A
Collector Dissipation	P _C		2	W
		T _C =25°C	20	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =-40V, I _E =0A			-10	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =-4V, I _C =0A			-10	μA
DC Current Gain	h _{FE1}	V _{CE} =-2V, I _C =-125mA	200		500	
	h _{FE2}	V _{CE} =-2V, I _C =-3.75A	50			
Gain-Bandwidth Product	f _T	V _{CE} =-10V, I _C =-300mA		130		MHz
Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz		55		pF

Continued on next page.

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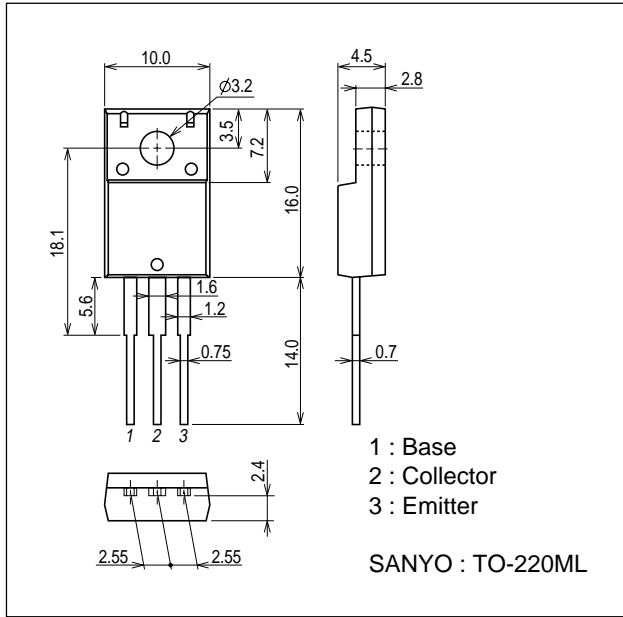
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -2.5A, I_B = -125mA$		-250	-500	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -2.5A, I_B = -125mA$			-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu A, I_E = 0A$	-50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -100\mu A, I_C = 0A$	-6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		75		ns
Storage Time	t_{stg}	See specified Test Circuit.		100		ns
Fall Time	t_f	See specified Test Circuit.		40		ns

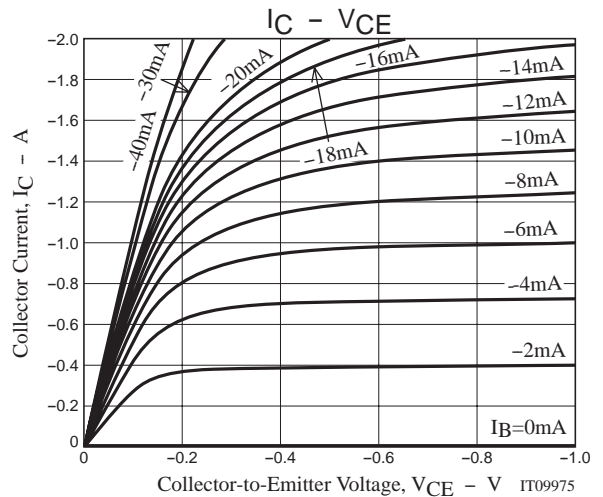
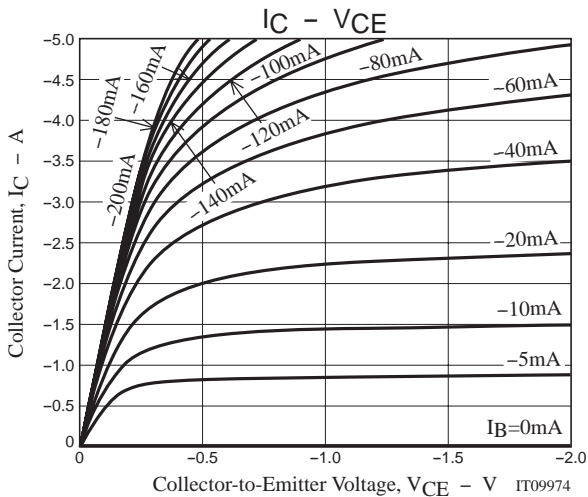
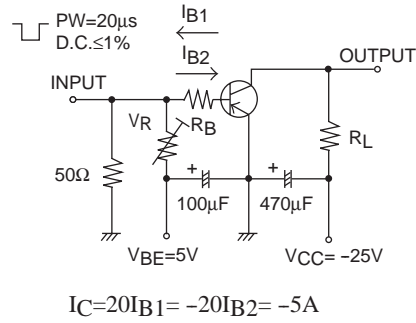
Package Dimensions

unit : mm

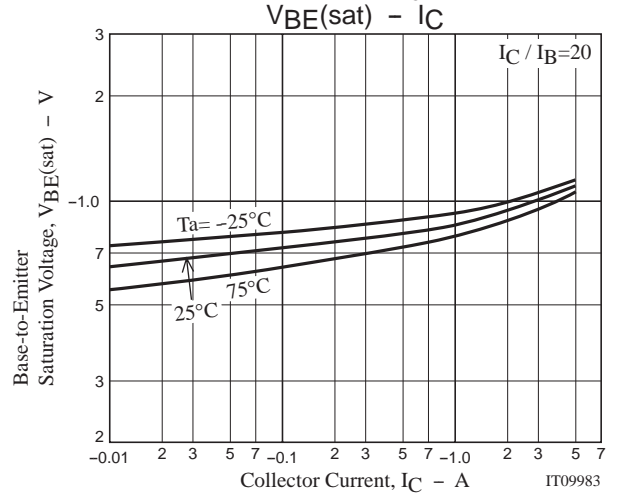
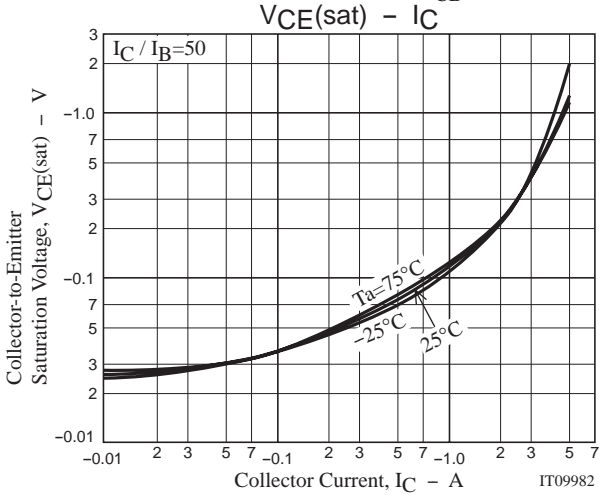
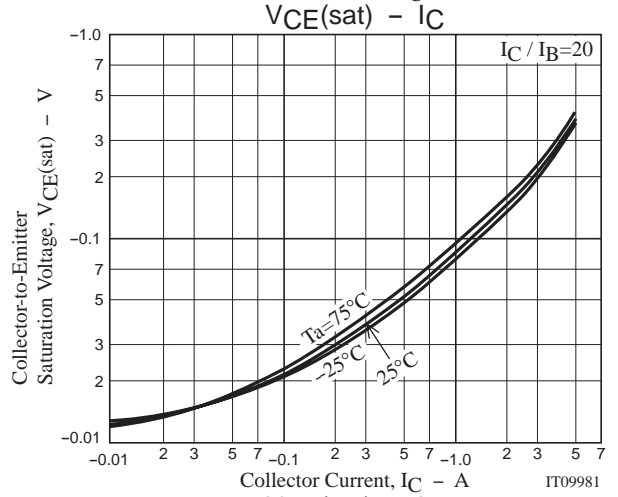
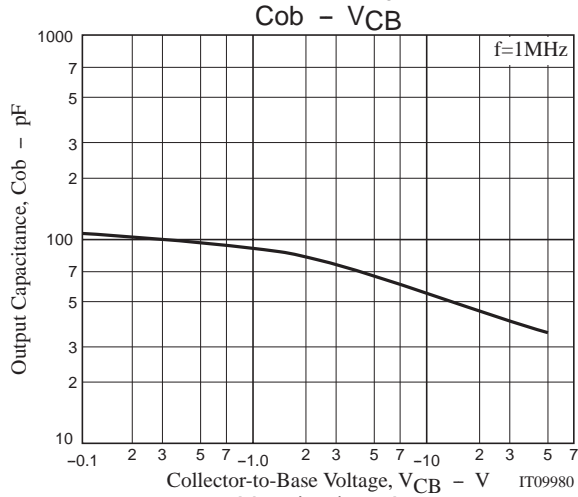
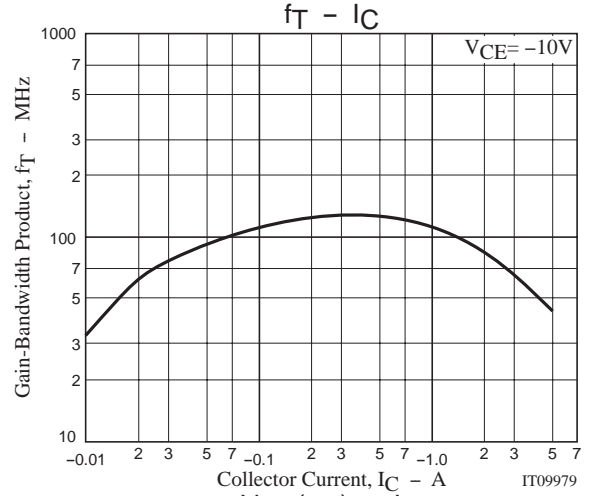
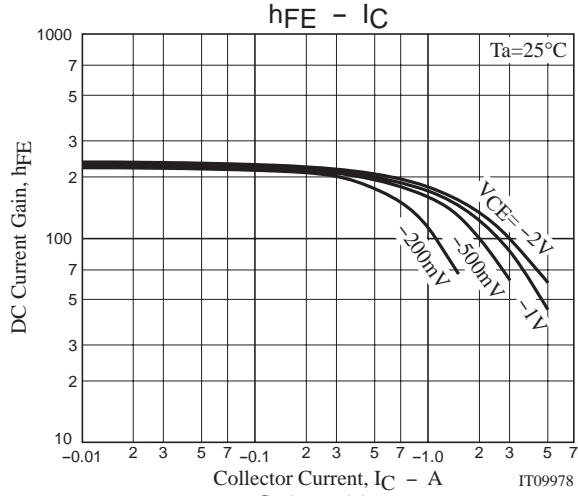
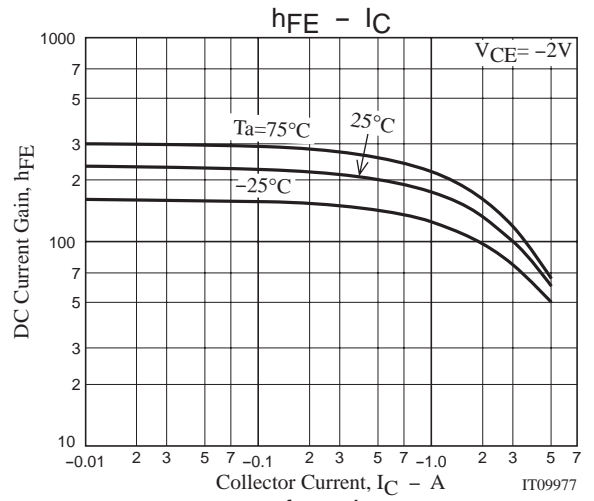
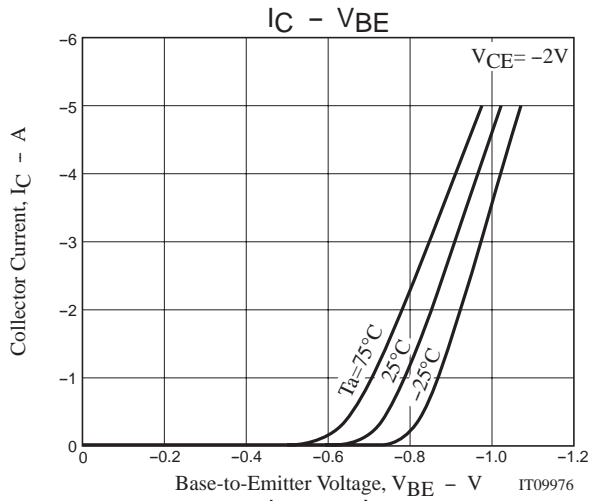
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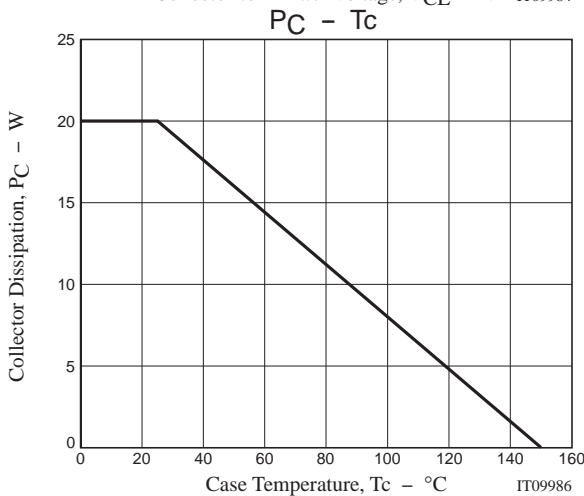
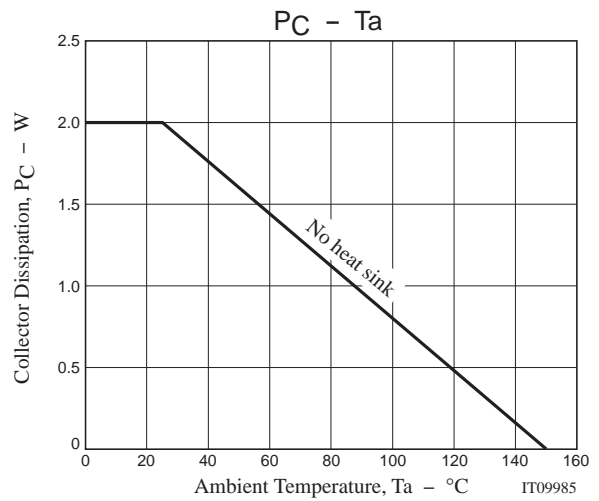
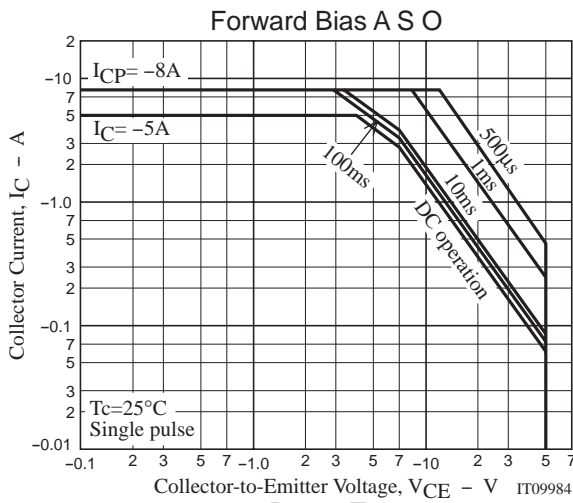


Switching Time Test Circuit



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